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TEXAS INSTRUMENTS

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SN54LVTH16373, SN74LVTH16373
3.3-V ABT 16-BIT TRANSPARENT D-TYPE LATCHES
WITH 3-STATE OUTPUTS

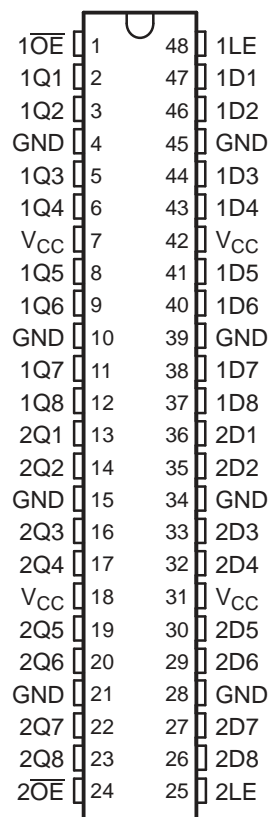SCBS144P−MAY 1992−REVISED NOVEMBER 2006

FEATURES

- **Members of the Texas Instruments Widebus™ Family**

- **State-of-the-Art Advanced BiCMOS Technology (ABT) Design for 3.3-V Operation and Low Static-Power Dissipation**

- **Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC})**

- **Support Unregulated Battery Operation Down to 2.7 V**

- **Typical V_{OLP} (Output Ground Bounce) <0.8 V at V_{CC} = 3.3 V, T_A = 25°C**

- **I_{off} and Power-Up 3-State Support Hot Insertion**

- **Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors**

- **Distributed V_{CC} and GND Pins Minimize High-Speed Switching Noise**

- **Flow-Through Architecture Optimizes PCB Layout**

- **Latch-Up Performance Exceeds 500 mA Per JESD 17**

- **ESD Protection Exceeds JESD 22**
  - **2000-V Human-Body Model (A114-A)**
  - **200-V Machine Model (A115-A)**

SN54LVTH16373 . . . WD PACKAGE
SN74LVTH16373 . . . DGG OR DL PACKAGE
(TOP VIEW)

1$\overline{OE}$	1	48	1LE
1Q1	2	47	1D1
1Q2	3	46	1D2
GND	4	45	GND
1Q3	5	44	1D3
1Q4	6	43	1D4
V_{CC}	7	42	V_{CC}
1Q5	8	41	1D5
1Q6	9	40	1D6
GND	10	39	GND
1Q7	11	38	1D7
1Q8	12	37	1D8
2Q1	13	36	2D1
2Q2	14	35	2D2
GND	15	34	GND
2Q3	16	33	2D3
2Q4	17	32	2D4
V_{CC}	18	31	V_{CC}
2Q5	19	30	2D5
2Q6	20	29	2D6
GND	21	28	GND
2Q7	22	27	2D7
2Q8	23	26	2D8
2$\overline{OE}$	24	25	2LE

DESCRIPTION/ORDERING INFORMATION

The 'LVTH16373 devices are 16-bit transparent D-type latches with 3-state outputs designed for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment. These devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

ORDERING INFORMATION

T_A	PACKAGE[1]		ORDERABLE PART NUMBER	TOP-SIDE MARKING
−40°C to 85°C	FBGA – GRD	Reel of 1000	SN74LVTH16373GRDR	LL373
	FBGA – ZRD (Pb-free)		SN74LVTH16373ZRDR	
	SSOP – DL	Tube of 25	SN74LVTH16373DL	LVTH16373
			SN74LVTH16373DLG4	
		Reel of 1000	SN74LVTH16373DLR	
			SN74LVTH16373DLRG4	
	TSSOP – DGG	Reel of 2000	SN74LVTH16373DGGR	LVTH16373
	VFBGA – GQL	Reel of 1000	SN74LVTH16373GQLR	LL373
	VFBGA – ZQL (Pb-free)		SN74LVTH16373ZQLR	

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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ORDERING INFORMATION (continued)

T_A	PACKAGE[1]		ORDERABLE PART NUMBER	TOP-SIDE MARKING
−55°C to 125°C	CFP − WD	Tube	SNJ54LVTH16373WD	SNJ54LVTH16373WD
			5962-9681001QXA	

DESCRIPTION/ORDERING INFORMATION (CONTINUED)

These devices can be used as two 8-bit latches or one 16-bit latch. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the levels set up at the D inputs.

A buffered output-enable ($\overline{OE}$) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without interface or pullup components.

$\overline{OE}$ does not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

When V_{CC} is between 0 and 1.5 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

These devices are fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.
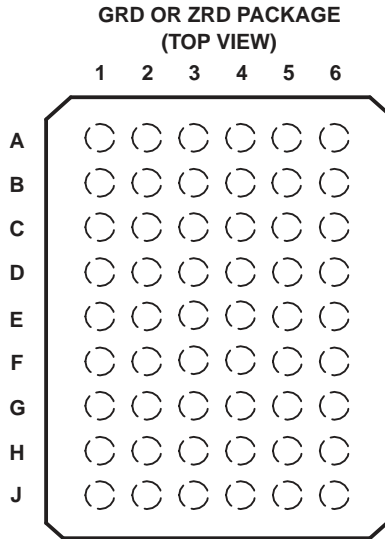
GQL OR ZQL PACKAGE
(TOP VIEW)
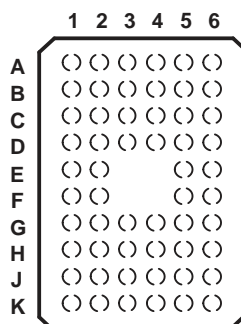
TERMINAL ASSIGNMENTS[1]
(56-Ball GQL/ZQL Package)

	1	2	3	4	5	6
A	1$\overline{OE}$	NC	NC	NC	NC	1CLK
B	1Q2	1Q1	GND	GND	1D1	1D2
C	1Q4	1Q3	V_{CC}	V_{CC}	1D3	1D4
D	1Q6	1Q5	GND	GND	1D5	1D6
E	1Q8	1Q7			1D7	1D8
F	2Q1	2Q2			2D2	2D1
G	2Q3	2Q4	GND	GND	2D4	2D3
H	2Q5	2Q6	V_{CC}	V_{CC}	2D6	2D5
J	2Q7	2Q8	GND	GND	2D8	2D7
K	2$\overline{OE}$	NC	NC	NC	NC	2CLK

(1) NC – No internal connection

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GRD OR ZRD PACKAGE
(TOP VIEW)

TERMINAL ASSIGNMENTS[1]
(54-Ball GRD/ZRD Package)

	1	2	3	4	5	6
A	1Q1	NC	1$\overline{\text{OE}}$	1LE	NC	1D1
B	1Q3	1Q2	NC	NC	1D2	1D3
C	1Q5	1Q4	V$_{CC}$	V$_{CC}$	1D4	1D5
D	1Q7	1Q6	GND	GND	1D6	1D7
E	2Q1	1Q8	GND	GND	1D8	2D1
F	2Q3	2Q2	GND	GND	2D2	2D3
G	2Q5	2Q4	V$_{CC}$	V$_{CC}$	2D4	2D5
H	2Q7	2Q6	NC	NC	2D6	2D7
J	2Q8	NC	2$\overline{\text{OE}}$	2LE	NC	2D8

(1) NC – No internal connection

FUNCTION TABLE
(8-BIT SECTION)

INPUTS			OUTPUT
$\overline{\text{OE}}$	CLK	D	Q
L	H	H	H
L	H	L	L
L	L	X	Q$_0$
H	X	X	Z

LOGIC DIAGRAM (POSITIVE LOGIC)

Pin numbers shown are for the DGG, DL, and WD packages.

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Absolute Maximum Ratings[1]

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		−0.5	4.6	V
V_I	Input voltage range[2]		−0.5	7	V
V_O	Voltage range applied to any output in the high-impedance or power-off state[2]		−0.5	7	V
V_O	Voltage range applied to any output in the high state[2]		−0.5	V_{CC} + 0.5	V
I_O	Current into any output in the low state	SN54LVTH16373		96	mA
		SN74LVTH16373		128	
I_O	Current into any output in the high state[3]	SN54LVTH16373		48	mA
		SN74LVTH16373		64	
I_{IK}	Input clamp current	V_I < 0		−50	mA
I_{OK}	Output clamp current	V_O < 0		−50	mA
θ_{JA}	Package thermal impedance[4]	DGG package		70	°C
		DL package		63	
		GQL/ZQL package		42	
		GRD/ZRD package		36	
T_{stg}	Storage temperature range		−65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
(3) This current flows only when the output is in the high state and V_O > V_{CC}.
(4) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions[1]

			SN54LVTH16373		SN74LVTH16373		UNIT
			MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage		2.7	3.6	2.7	3.6	V
V_{IH}	High-level input voltage		2		2		V
V_{IL}	Low-level input voltage			0.8		0.8	V
V_I	Input voltage			5.5		5.5	V
I_{OH}	High-level output current			−24		−32	mA
I_{OL}	Low-level output current			48		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outpts enabled		10		10	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate		200		200		μs/V
T_A	Operating free-air temperature		−55	125	−40	85	°C

(1) All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54LVTH16373			SN74LVTH16373			UNIT
				MIN	TYP[1]	MAX	MIN	TYP[1]	MAX	
V_{IK}		V_{CC} = 2.7 V,	I_I = −18 mA			−1.2			−1.2	V
V_{OH}		V_{CC} = 2.7 V to 3.6 V,	I_{OH} = −100 μA	V_{CC} − 0.2			V_{CC} − 0.2			V
		V_{CC} = 2.7 V,	I_{OH} = −8 mA	2.4			2.4			
		V_{CC} = 3 V	I_{OH} = −24 mA	2						
			I_{OH} = −32 mA				2			
V_{OL}		V_{CC} = 2.7 V	I_{OL} = 100 μA			0.2			0.2	V
			I_{OL} = 24 mA			0.5			0.5	
		V_{CC} = 3 V	I_{OL} = 16 mA			0.4			0.4	
			I_{OL} = 32 mA			0.5			0.5	
			I_{OL} = 48 mA			0.55				
			I_{OL} = 64 mA						0.55	
I_I		V_{CC} = 0 or 3.6 V,	V_I = 5.5 V			10			10	μA
	Control inputs	V_{CC} = 3.6 V,	V_I = V_{CC} or GND			±1			±1	
	Data inputs	V_{CC} = 3.6 V	V_I = V_{CC}			1			1	
			V_I = 0			−5			−5	
I_{off}		V_{CC} = 0,	V_I or V_O = 0 to 4.5 V						±100	μA
$I_{I(hold)}$	Data inputs	V_{CC} = 3 V	V_I = 0.8 V	75			75			μA
			V_I = 2 V	−75			−75			
		V_{CC} = 3.6 V,[2]	V_I = 0 to 3.6 V						±500	
I_{OZH}		V_{CC} = 3.6 V,	V_O = 3 V			5			5	μA
I_{OZL}		V_{CC} = 3.6 V,	V_O = 0.5 V			−5			−5	μA
I_{OZPU}		V_{CC} = 0 to 1.5 V, V_O = 0.5 V to 3 V, $\overline{OE}$ = don't care				±100[3]			±100	μA
I_{OZPD}		V_{CC} = 1.5 V to 0, V_O = 0.5 V to 3 V, $\overline{OE}$ = don't care				±100[3]			±100	μA
I_{CC}		V_{CC} = 3.6 V, I_O = 0, V_I = V_{CC} or GND	Outputs high			0.19			0.19	mA
			Outputs low			5			5	
			Outputs disabled			0.19			0.19	
ΔI_{CC}[4]		V_{CC} = 3 V to 3.6 V, One input at V_{CC} − 0.6 V, Other inputs at V_{CC} or GND				0.2			0.2	mA
C_i		V_I = 3 V or 0			3			3		pF
C_o		V_O = 3 V or 0			9			9		pF

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25°C.
(2) This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.
(3) On products compliant to MIL-PRF-38535, this parameter is not production tested.
(4) This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.

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Timing Requirements

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

		SN54LVTH16373				SN74LVTH16373				UNIT
		V_{CC} = 3.3 V $\pm$ 0.3 V		V_{CC} = 2.7 V		V_{CC} = 3.3 V $\pm$ 0.3 V		V_{CC} = 2.7 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_w	Pulse duration, LE high	3		3		3		3		ns
t_{su}	Setup time, data before LE$\downarrow$	2		2		1		0.6		ns
t_h	Hold time, data after LE$\downarrow$	3		3.3		1		1.1		ns

Switching Characteristics

over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN54LVTH16373				SN74LVTH16373					UNIT
			V_{CC} = 3.3 V $\pm$ 0.3 V		V_{CC} = 2.7 V		V_{CC} = 3.3 V $\pm$ 0.3 V			V_{CC} = 2.7 V		UNIT
			MIN	MAX	MIN	MAX	MIN	TYP[1]	MAX	MIN	MAX	
t_{PLH}	D	Q	1.4	4.5		5.2	1.5	2.7	3.8		4.2	ns
t_{PHL}			1.4	4.4		4.8	1.5	2.5	3.6		4	
t_{PLH}	LE	Q	1.8	5.5		5.8	2.1	3	4.3		4.8	ns
t_{PHL}			1.8	5.2		5.6	2.1	2.9	4		4	
t_{PZH}	$\overline{OE}$	Q	1.4	5.7		6.7	1.5	2.8	4.3		5.1	ns
t_{PZL}			1.4	5.5		6	1.5	2.8	4.3		4.7	
t_{PHZ}	$\overline{OE}$	Q	2	6		6.2	2.4	3.5	5		5.4	ns
t_{PLZ}			1.4	5.2		5.6	2	3.2	4.7		4.8	
$t_{sk(LH)}$									0.5			ns
$t_{sk(HL)}$									0.5			

(1)   All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

PARAMETER MEASUREMENT INFORMATION
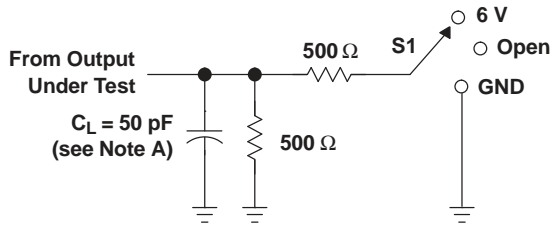
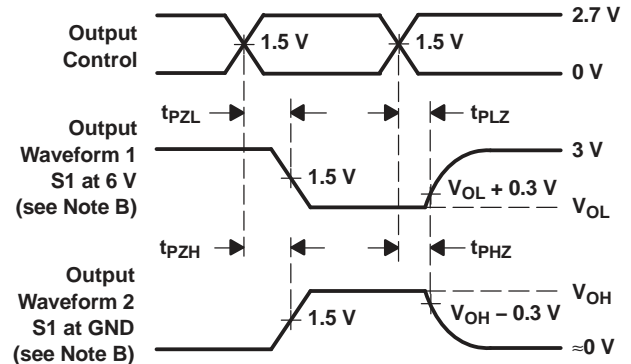| TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	6 V
t_{PHZ}/t_{PZH}	GND

LOAD CIRCUIT
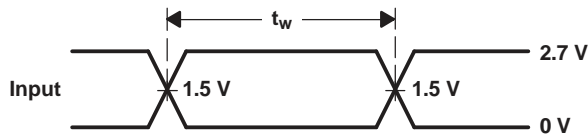
**VOLTAGE WAVEFORMS
PULSE DURATION**
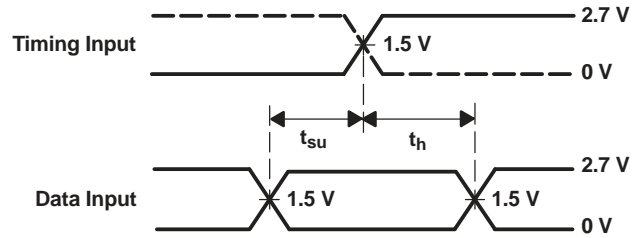
**VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES**
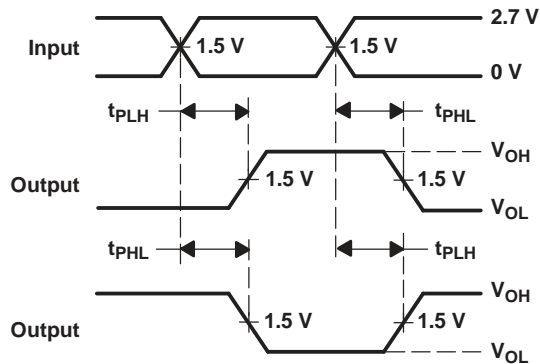
**VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS**

**VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING**

NOTES: A. C_L includes probe and jig capacitance.
   B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.
      Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
   C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O = 50\ \Omega$, $t_r \le 2.5$ ns, $t_f \le 2.5$ ns.
   D. The outputs are measured one at a time, with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9681001QXA	ACTIVE	CFP	WD	48	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9681001QX A SNJ54LVTH16373 WD	Samples
SN74LVTH16373DGGR	ACTIVE	TSSOP	DGG	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16373	Samples
SN74LVTH16373DL	ACTIVE	SSOP	DL	48	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16373	Samples
SN74LVTH16373DLR	ACTIVE	SSOP	DL	48	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16373	Samples
SNJ54LVTH16373WD	ACTIVE	CFP	WD	48	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9681001QX A SNJ54LVTH16373 WD	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54LVTH16373, SN74LVTH16373 :

● Catalog : SN74LVTH16373

● Enhanced Product : SN74LVTH16373-EP, SN74LVTH16373-EP

● Military : SN54LVTH16373

NOTE: Qualified Version Definitions:

 ● Catalog - TI's standard catalog product

 ● Enhanced Product - Supports Defense, Aerospace and Medical Applications

 ● Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH16373DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1
SN74LVTH16373DLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVTH16373DGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0
SN74LVTH16373DLR	SSOP	DL	48	1000	367.0	367.0	55.0

PACKAGE MATERIALS INFORMATION

TUBE

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74LVTH16373DL	DL	SSOP	48	25	473.7	14.24	5110	7.87

WD (R-GDFP-F**)   **CERAMIC DUAL FLATPACK**

48 LEADS SHOWN
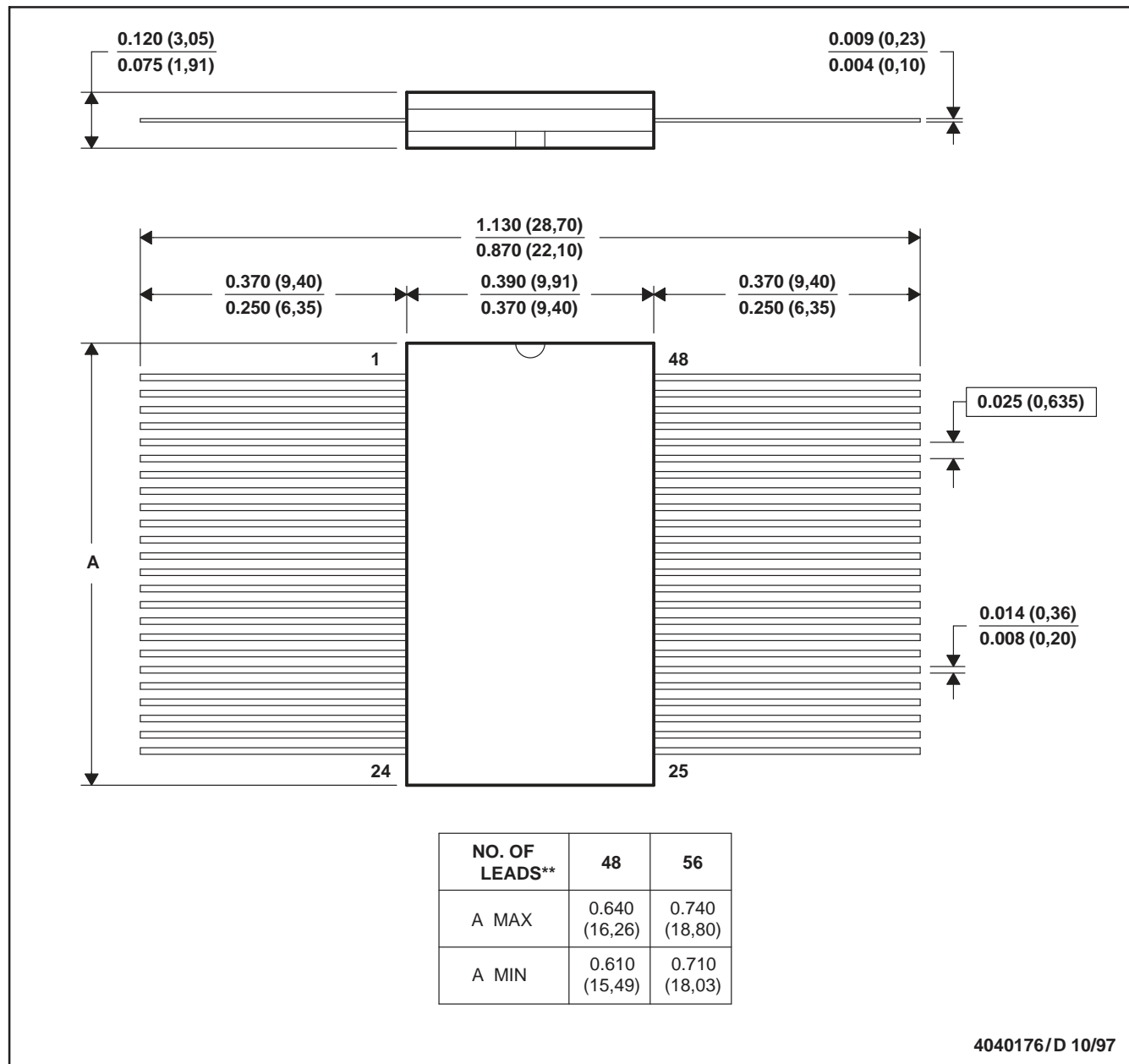
NO. OF LEADS**	48	56
A MAX	0.640 (16,26)	0.740 (18,80)
A MIN	0.610 (15,49)	0.710 (18,03)

4040176 / D 10/97

NOTES: A. All linear dimensions are in inches (millimeters).
           B. This drawing is subject to change without notice.
           C. This package can be hermetically sealed with a ceramic lid using glass frit.
           D. Index point is provided on cap for terminal identification only
           E. Falls within MIL STD 1835: GDFP1-F48 and JEDEC MO-146AA
                                                   GDFP1-F56 and JEDEC MO-146AB

DL (R−PDSO−G48)   PLASTIC SMALL−OUTLINE PACKAGE
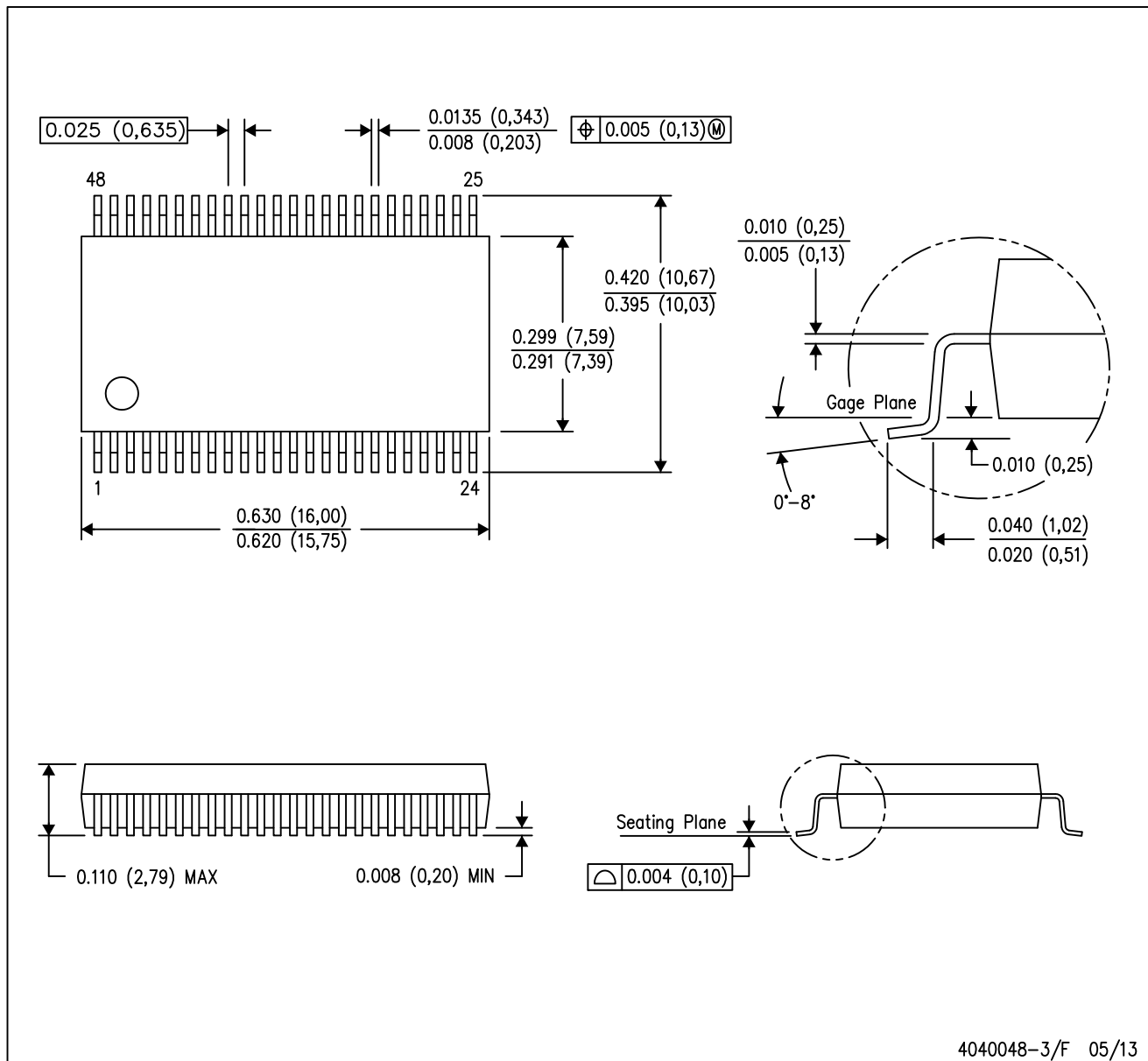
0.025 (0,635)

$\dfrac{0.0135\ (0,343)}{0.008\ (0,203)}$ ⊕ 0.005 (0,13) Ⓜ

48   25

$\dfrac{0.420\ (10,67)}{0.395\ (10,03)}$

$\dfrac{0.299\ (7,59)}{0.291\ (7,39)}$

$\dfrac{0.010\ (0,25)}{0.005\ (0,13)}$

Gage Plane

0°−8°

0.010 (0,25)

1   24

$\dfrac{0.630\ (16,00)}{0.620\ (15,75)}$

$\dfrac{0.040\ (1,02)}{0.020\ (0,51)}$

0.110 (2,79) MAX   0.008 (0,20) MIN

Seating Plane

△ 0.004 (0,10)

4040048−3/F   05/13

NOTES: A.   All linear dimensions are in inches (millimeters).
         B.   This drawing is subject to change without notice.
         C.   Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
         D.   Falls within JEDEC MO−118

PowerPAD is a trademark of Texas Instruments.

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8.3
7.9 TYP

A

PIN 1 ID
AREA

1

48

46X 0.5

12.6
12.4
NOTE 3

2X
11.5

24

25

B

6.2
6.0

48X 0.27
0.17

⊕ 0.08 Ⓜ C A B

C

SEATING PLANE

⌒ 0.1 C

1.2
1.0

(0.15) TYP

SEE DETAIL A

0.25

GAGE PLANE

0° - 8°

0.75
0.50

0.15
0.05

DETAIL A
TYPICAL

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NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-153.

48X (1.5)

SYMM

1

48X (0.3)

48

46X (0.5)

(R0.05)
TYP

SYMM

24

25

(7.5)

LAND PATTERN EXAMPLE
SCALE:6X

SOLDER MASK
OPENING

METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

0.05 MAX
ALL AROUND

0.05 MIN
ALL AROUND

NON SOLDER MASK
DEFINED

SOLDER MASK
DEFINED
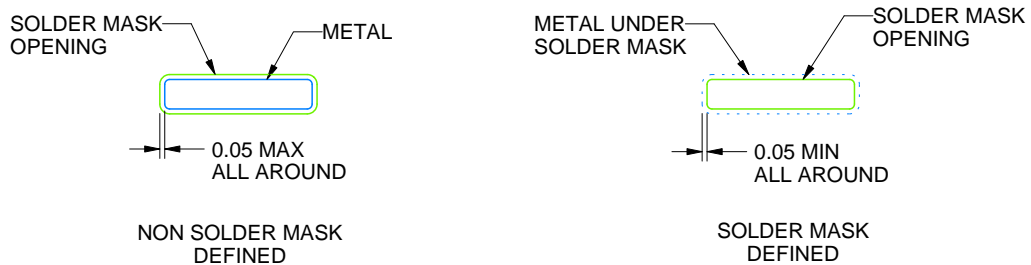
SOLDER MASK DETAILS

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NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

48X (1.5)

1

48X (0.3)

46X (0.5)

(R0.05) TYP

SYMM

48

SYMM

24

25

(7.5)
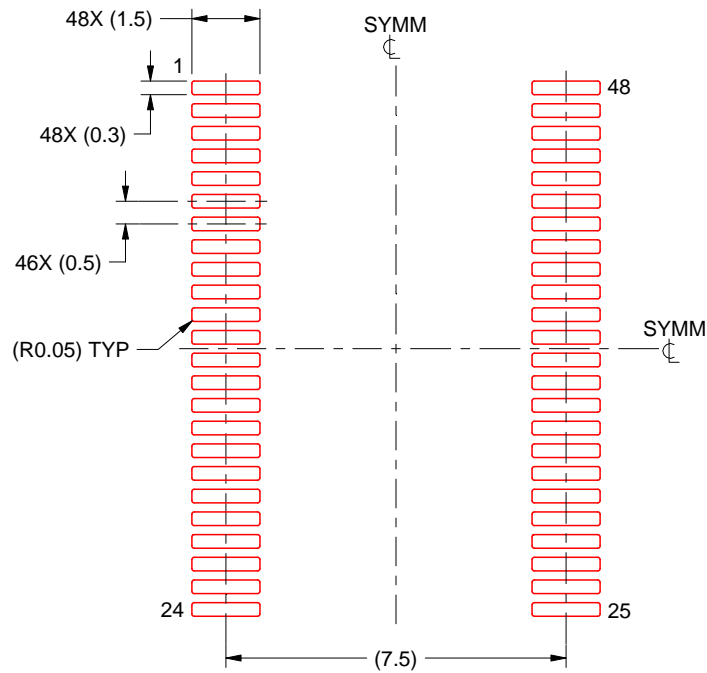
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:6X

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NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

DGG (R-PDSO-G**)   **PLASTIC SMALL-OUTLINE PACKAGE**

48 PINS SHOWN

PINS ** DIM	48	56	64
A MAX	12,60	14,10	17,10
A MIN	12,40	13,90	16,90

4040078 / F 12/97
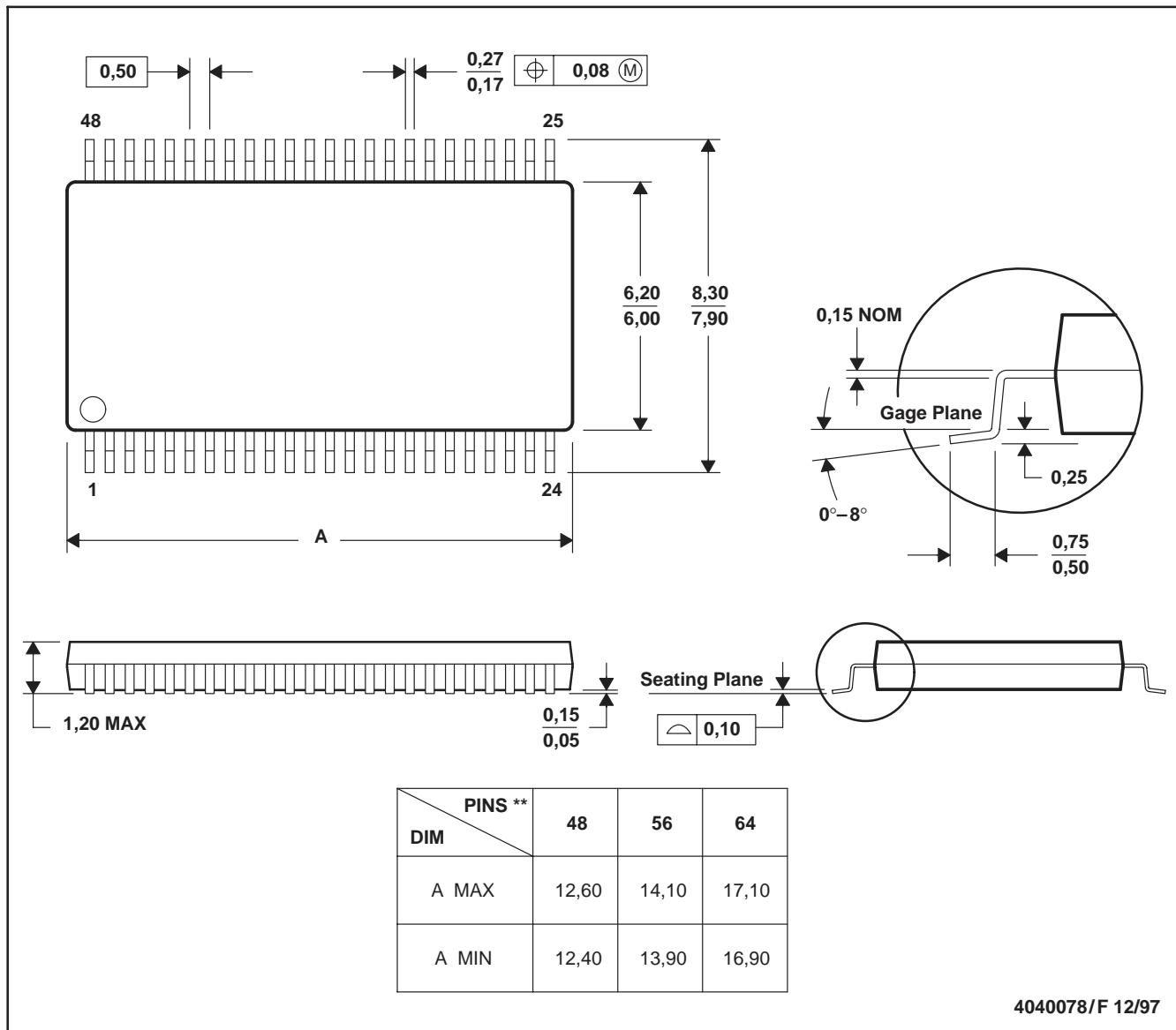
NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold protrusion not to exceed 0,15.
D. Falls within JEDEC MO-153

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